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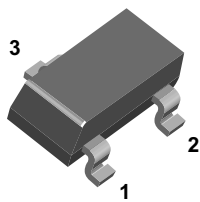
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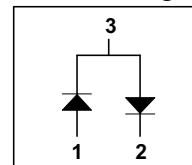
# BAS31 Small Signal Diode



SOT-23



Connection Diagram



## Ordering Information

Part Number	Top Mark	Package	Packing Method
BAS31	L21	SOT-23 3L	Tape and Reel, 7 inch Reel, 3000 pcs
BAS31-D87Z	L21	SOT-23 3L	Tape and Reel, 13 inch Reel, 10000 pcs

## Absolute Maximum Ratings<sup>(1), (2)</sup>

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only. Values are at  $T_A = 25^\circ\text{C}$  unless otherwise noted.

Symbol	Parameter	Value	Unit
$V_{RRM}$	Maximum Repetitive Reverse Voltage	120	V
$I_{F(AV)}$	Average Rectified Forward Current	200	mA
$I_{FSM}$	Non-Repetitive Peak Forward Surge Current	Pulse Width = 1.0 second	1.0
		Pulse Width = 1.0 microsecond	2.0
$T_{STG}$	Storage Temperature Range	-55 to +150	$^\circ\text{C}$
$T_J$	Operating Junction Temperature	150	$^\circ\text{C}$

### Notes:

1. These ratings are based on a maximum junction temperature of  $150^\circ\text{C}$ .
2. These are steady-state limits. ON Semiconductor should be consulted on applications involving pulsed or low-duty-cycle operations.

### Thermal Characteristics

Values are at  $T_A = 25^\circ\text{C}$  unless otherwise noted.

Symbol	Parameter	Value	Unit
$P_D$	Power Dissipation	350	mW
$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient	357	$^\circ\text{C}/\text{W}$

### Electrical Characteristics

Values are at  $T_A = 25^\circ\text{C}$  unless otherwise noted.

Symbol	Parameter	Conditions	Min.	Max.	Unit
$V_R$	Breakdown Voltage	$I_R = 1.0 \text{ mA}$	120		V
$V_F$	Forward Voltage	$I_F = 10 \text{ mA}$		750	mV
		$I_F = 50 \text{ mA}$		840	mV
		$I_F = 100 \text{ mA}$		900	mV
		$I_F = 200 \text{ mA}$		1.00	V
		$I_F = 400 \text{ mA}$		1.25	V
$I_R$	Reverse Current	$V_R = 90 \text{ V}$		100	nA
		$V_R = 90 \text{ V}, T_A = 150^\circ\text{C}$		100	$\mu\text{A}$
$C_T$	Total Capacitance	$V_R = 0, f = 1.0 \text{ MHz}$		35	pF
$t_{rr}$	Reverse Recovery Time	$I_F = I_R = 30 \text{ mA}, I_{RR} = 3.0 \text{ mA}, R_L = 100 \Omega$		50	ns

## Typical Performance Characteristics

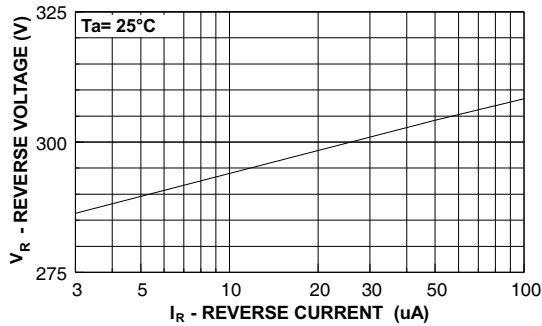


Figure 1. Reverse Voltage vs. Reverse Current  
BV - 1.0 to 100  $\mu$ A

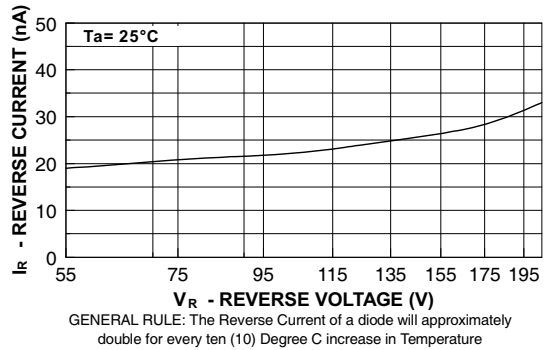


Figure 2. Reverse Current vs. Reverse Voltage  
 $I_R$  - 55 to 205 V

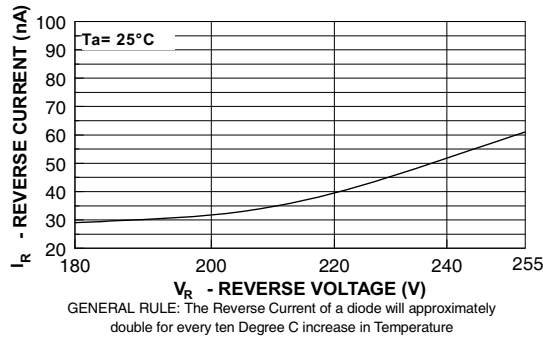


Figure 3. Reverse Current vs. Reverse Voltage  
 $I_R$  - 180 to 255 V

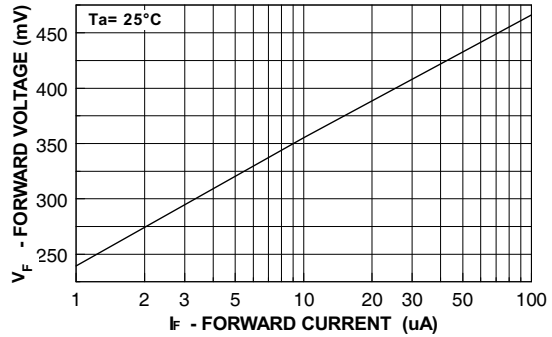


Figure 4. Forward Voltage vs. Forward Current  
 $V_F$  - 1.0 to 100  $\mu$ A

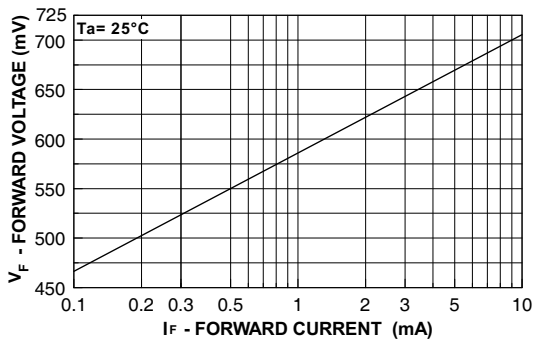


Figure 5. Forward Voltage vs. Forward Current  
 $V_F$  - 0.1 to 10 mA

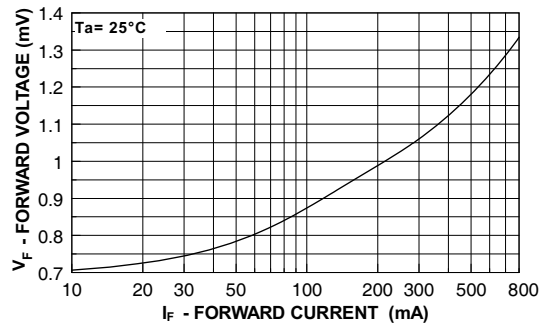


Figure 6. Forward Voltage vs. Forward Current  
 $V_F$  - 10 to 800 mA

Typical Performance Characteristics (Continued)

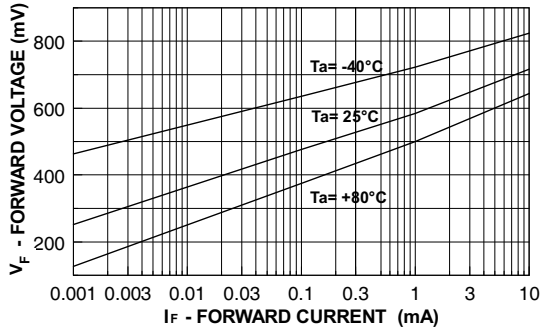


Figure 7. Forward Voltage vs. Ambient Temperature  
 $V_F$  - 1.0  $\mu$ A - 10 mA (- 40 to +80°C)

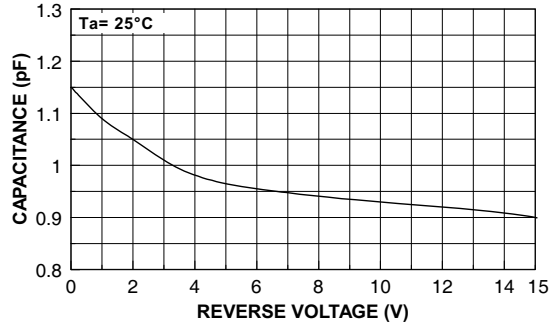


Figure 8. Capacitance vs. Reverse Voltage

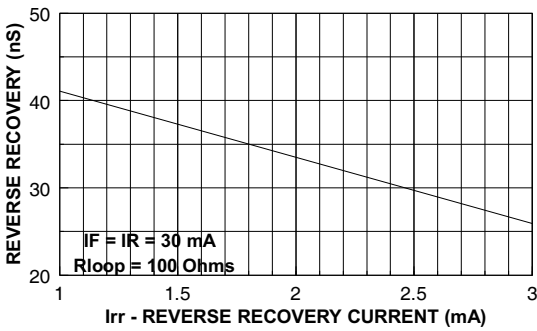


Figure 9. Reverse Recovery Time vs. Reverse Recovery Current ( $I_{rr}$ )

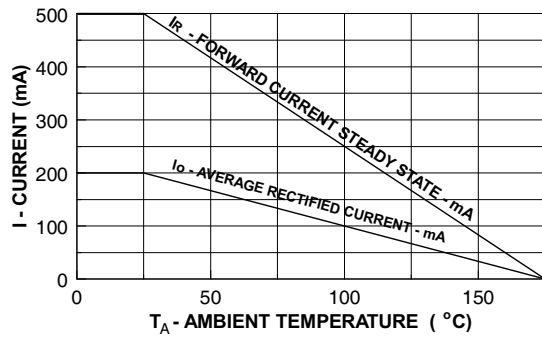


Figure 10. Average Rectified Current ( $I_O$ ) and Forward Current ( $I_F$ ) vs. Ambient Temperature ( $T_A$ )

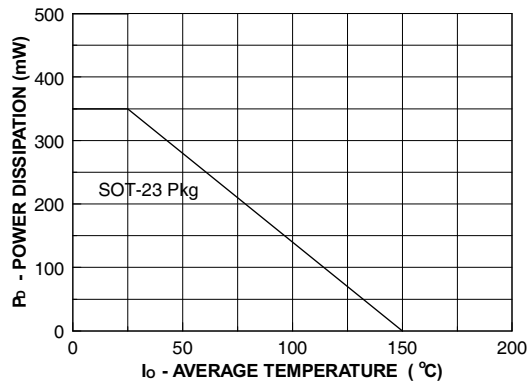


Figure 11. Power Derating Curve

Physical Dimensions

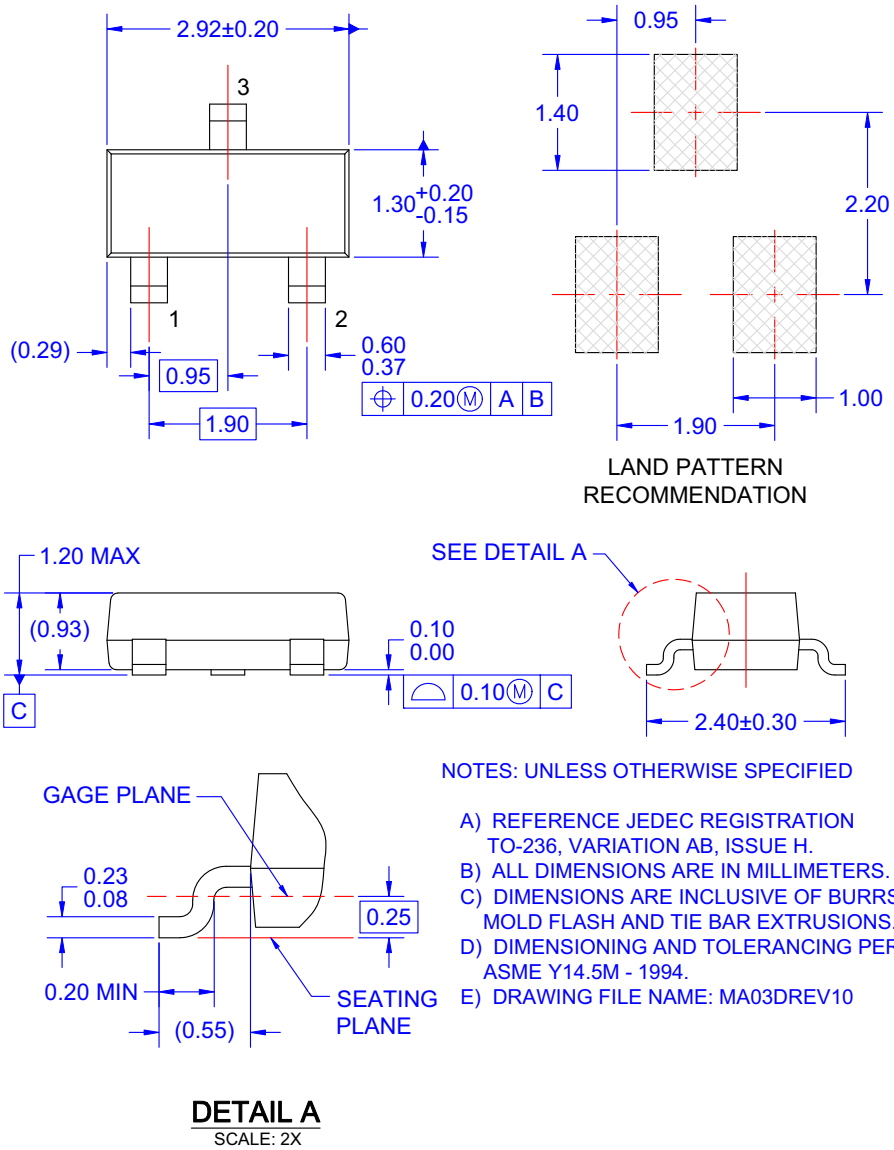


Figure 12. 3-LEAD, SOT23, JEDEC TO-236, LOW PROFILE

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